



# The **FACT** Project

## **F**irst **G-APD** **C**herenkov **T**elescope

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for the FACT Collaboration:

TU Dortmund, U Geneva,  
EPF Lausanne, U Wuerzburg  
ETH Zurich

# The **FACT** Project

## Key Question:

can newly developed Si-based photosensors [G-APD, SiPM, MPPC,...] be used in Cherenkov Telescopes ?

- reduction of operation complexity (less fragile, no HV)
- stable remote operation
- eventually lower cost and higher efficiency by profiting from development for large market for Si-based technology

## Main Problem:

PMTs and G-APD have rather different features

=> 'difficult' to compare datasheets

## Solution:

Build a CT using new photosensors and try

=> **F**irst **G-APD** **C**herenkov **T**elescope

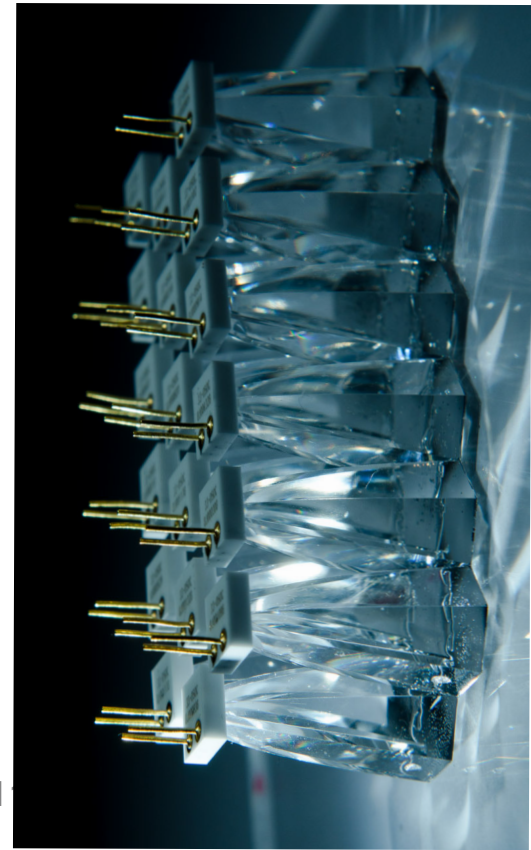
# The **FACT** Project

## Main Components:

- Refurbished HEGRA CT3 telescope at LaPalma  
(9.2m<sup>2</sup> mirror area,  $f/d = 1.4$ , new drive system)

## Camera:

- G-APDs (HAMAMATSU MPPC S10362-33-050C)
- Solid Light-Concentrators
- Electronics (DRS-4 based) in camera
- readout using standard ethernet





## Refurbished HEGRA-CT3 Telescope at La Palma:

- new mirrors installed (refurbished from CT1)
- new drive system installed
- new container as 'counting house'
- awaiting camera ....



9.2m<sup>2</sup> mirror area (next to MAGIC with 2x 236m<sup>2</sup> mirror...)



# G-APD Basics

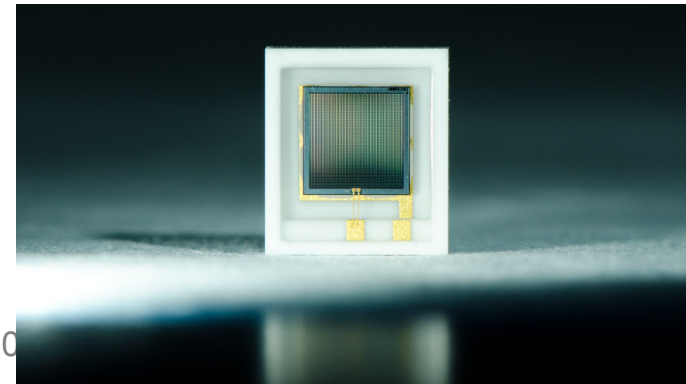
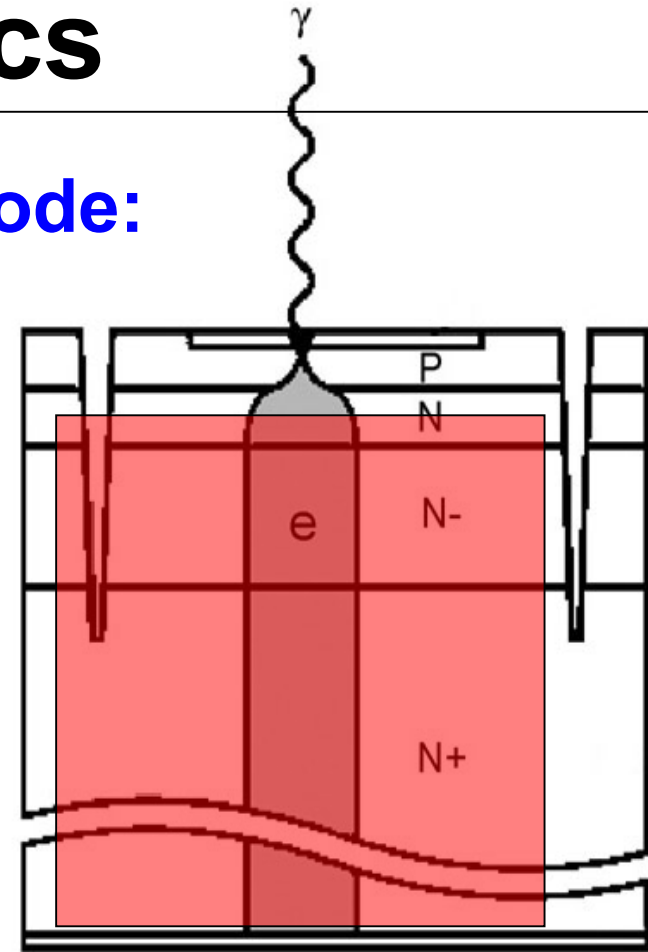
## Geiger-mode Avalanche Photodiode:

(also called: SiPM, MPPC, PPD, ...)

Pixelized Si-based photosensor:  
a (single) photon hitting a cell has  
some probability to create a  
'breakdown' -> always same signal

Many small cells ==>  
total signal analogue sum of the  
isochronous single-cell signals

cell-sizes  $O(100 \times 100 \mu\text{m}^2)$



# G-APD Basics



## Typical values:

Bias Voltage: 50-100 V (no HV needed !)

Gain:  $10^5 \dots 10^7$

Photo-detection efficiency: 30...40 % (?)

[wavelength dependent]

no ageing (even if accidentally exposed to daylight)

[but limited long-time experience]

## several manufacturers:

CPTA/Photonique, Perkin-Elmer, Hamamatsu, Zecotec, MPI Semiconductor Lab, ...



# G-APD Features

**Saturation** (if  $\gg 10\%$  of cells occupied; NSB!!!)

larger cell size  $\rightarrow$  higher PDE (less dead area)  
but also worse saturation

*FACT: use  $50 \times 50 \mu\text{m}^2$  to be able to run with high NSB*

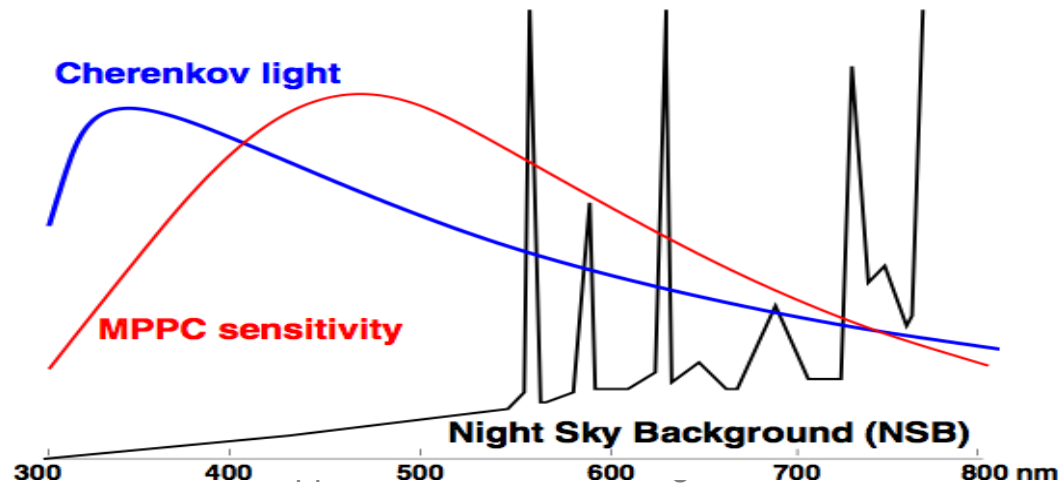
**Temperature dependent gain** (  $\sim 5\%$  / degree )

$\Rightarrow$  temperature stabilization or

*gain stabilization via feedback system*

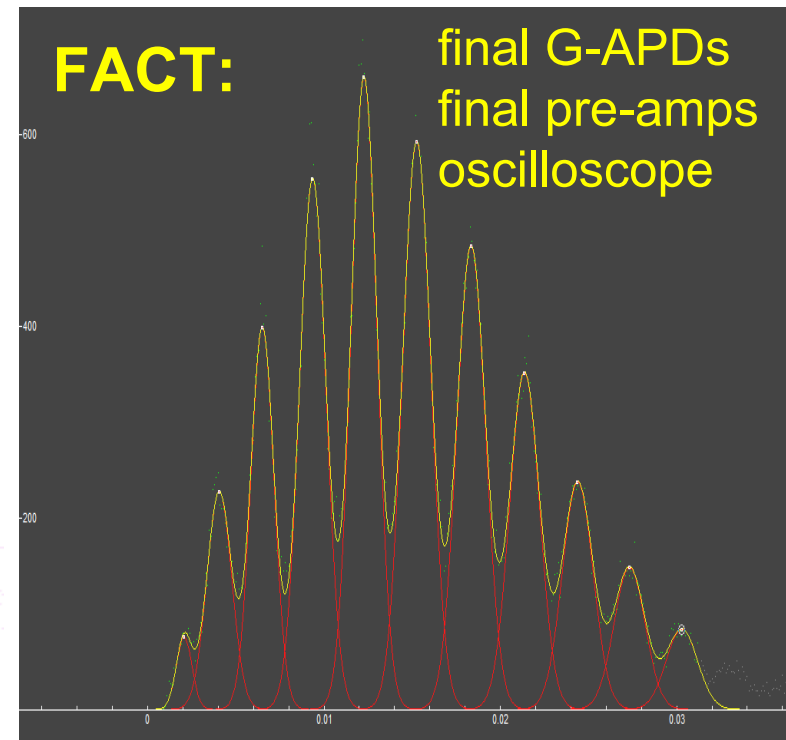
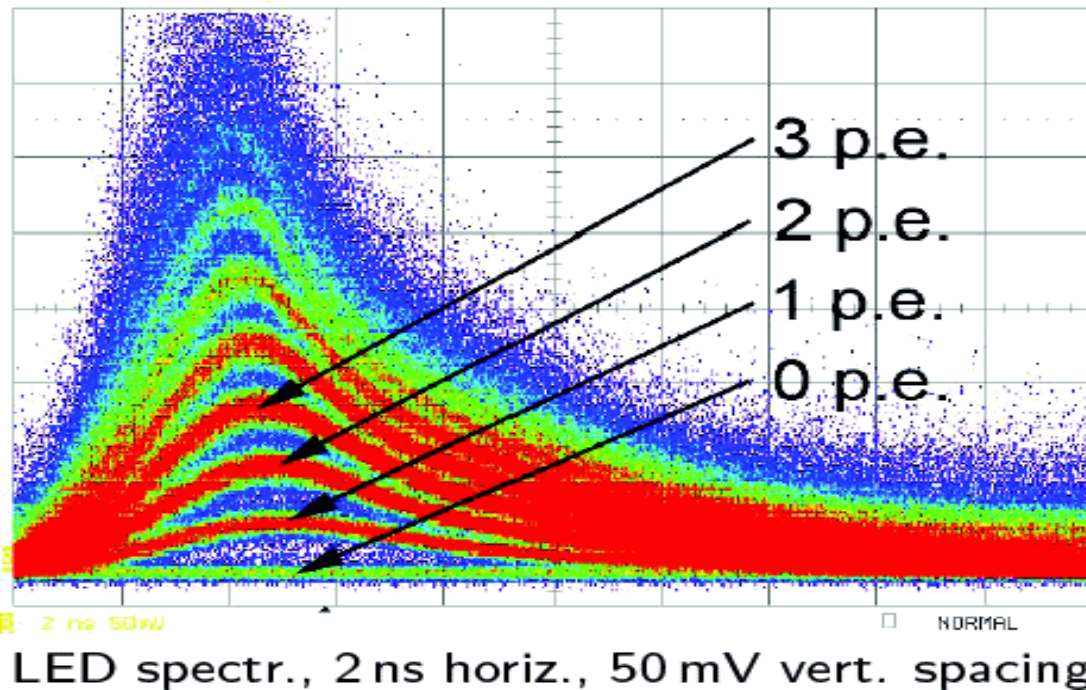
**Sensitive also  $\gg 700\text{nm}$**

( $\Rightarrow$  more NSB)



# G-APD Features

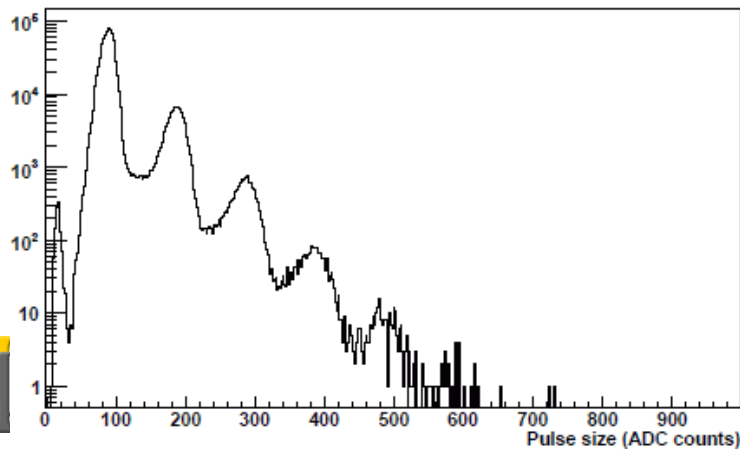
slower rise and decay time than best PMTs,  
but very constant signals (if constant gain)





# G-APD Features

- Dark counts
  - Cells can be triggered by any free carrier, eg. thermally generated or field assisted tunneling.
  - Rate: some 100 kHz up to MHz per  $\text{mm}^2$  at room temperature.
- Afterpulses
  - The delayed release of carriers trapped during a breakdown in a cell can trigger the cell again.
  - Afterpulse probability 5 – 20% depending on the gain.
- Crosstalk
  - Defines the spectrum of the two phenomena above.
  - Crosstalk probability 5 – 20% depending on the gain.

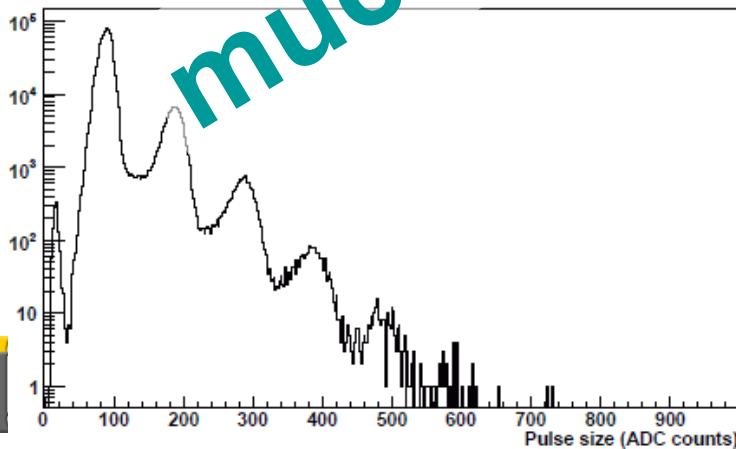


Typical dark count spectrum of a G-APD (crosstalk 13%). Peaks up to 6 triggered cells can be discerned. The spectrum also includes afterpulses of previous dark count events.

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much worse than PMTs ???

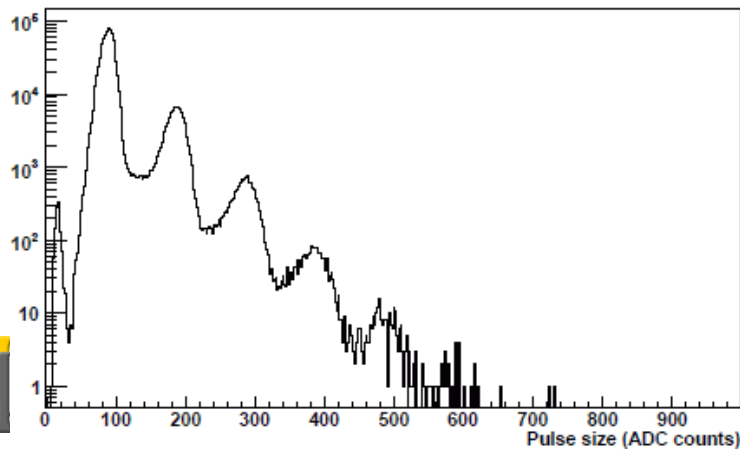


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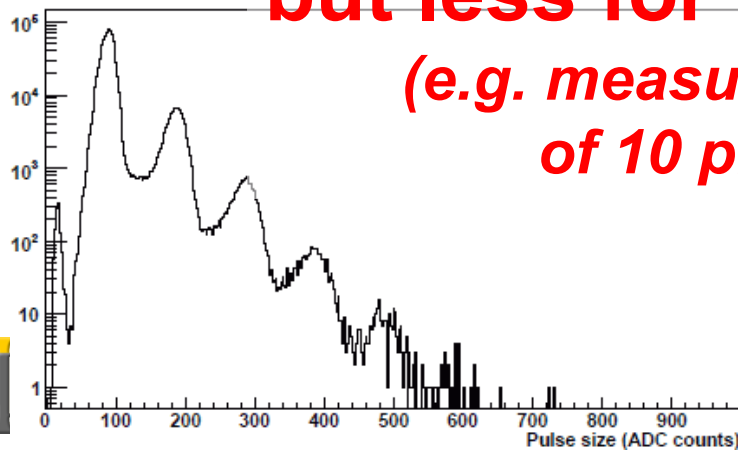
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**important for single photon counting,  
but less for CTs: can be calibrated**

**(e.g. measure on average 11 instead  
of 10 p.e. for 10% Crosstalk)**

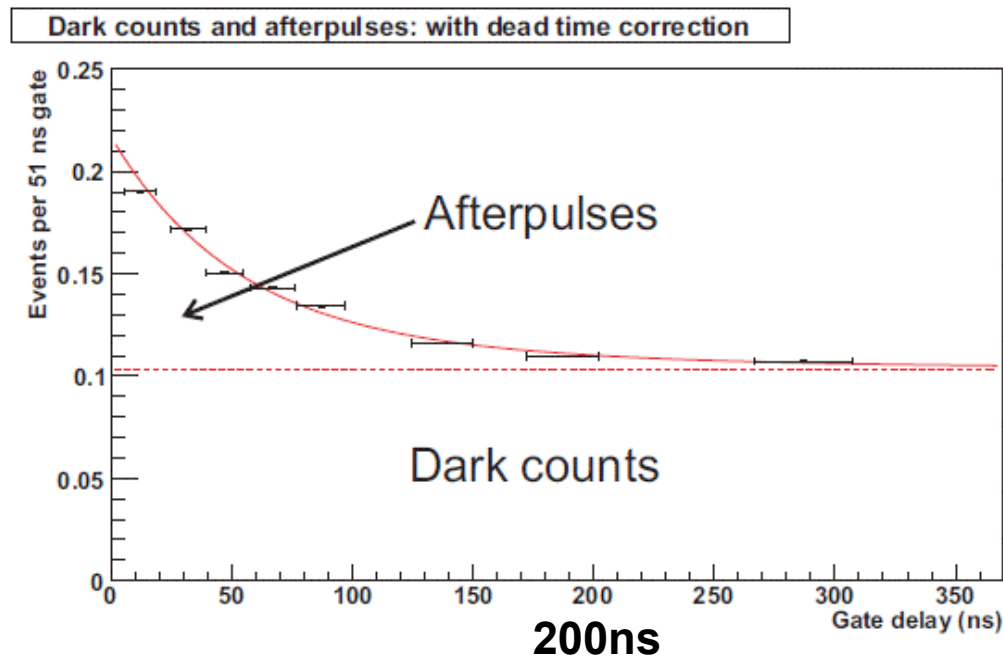


Typical dark count spectrum of a G-APD (crosstalk 15%). Peaks up to 6 triggered cells can be discerned. The spectrum also includes afterpulses of previous dark count events.



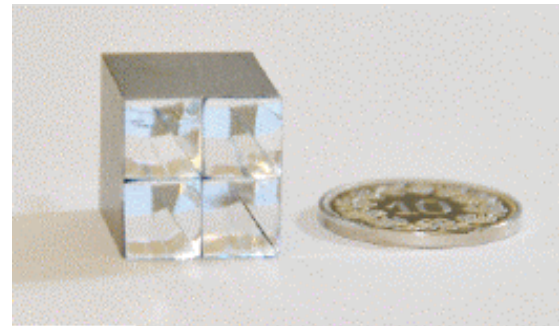
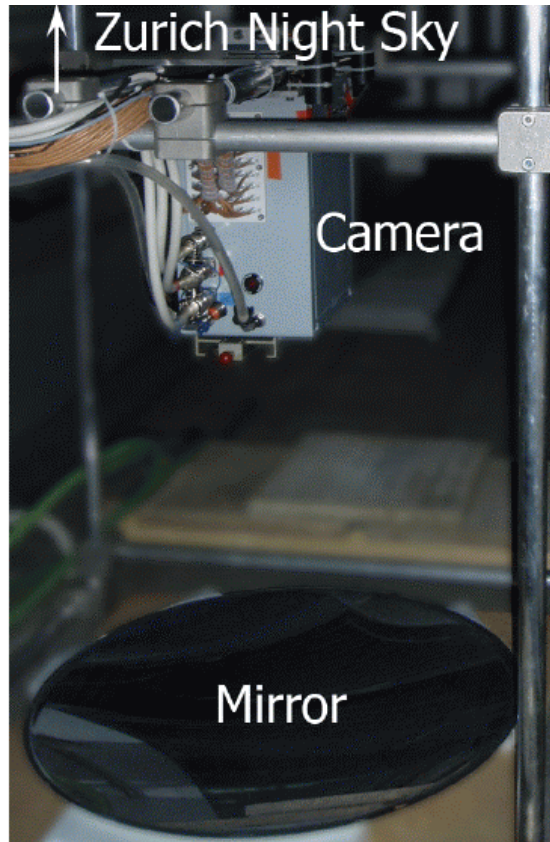
# G-APD Features

- Dark counts have a random time distribution.
- Afterpulses have an exponentially decreasing probability after an initial breakdown.

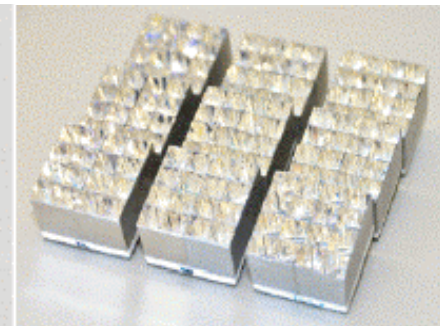


Number of pulses per gate for variable delays after an initial pulse. The number of pulses decreases exponentially to the level of dark counts.

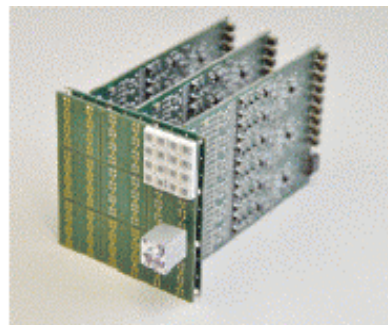
# Prototype Camera (2009)



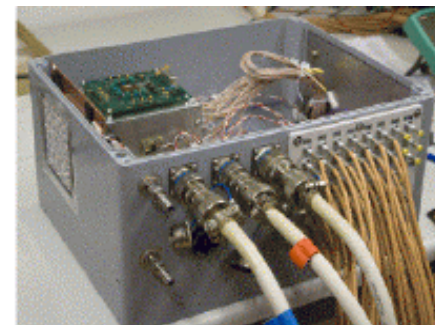
Hollow Cone:  $(7.2 \text{ mm})^2 \rightarrow (2.8 \text{ mm})^2$   
1 cone per G-APD, blocks of 4



4 G-APDs/pixel = 1 channel  
36 pixels, each  $(14.4 \text{ mm})^2$



3 analog preamplifier boards  
Distribution of bias voltage

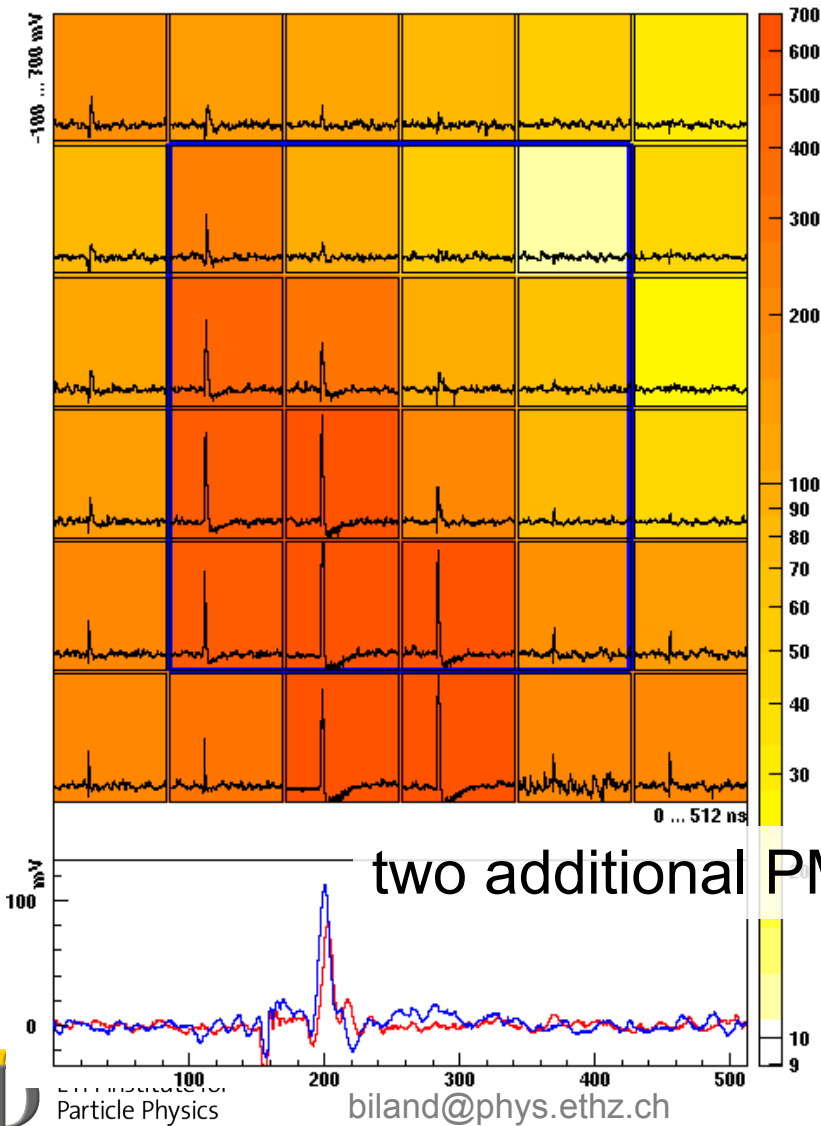


Light and rain-tight box  
Analog signal transfer

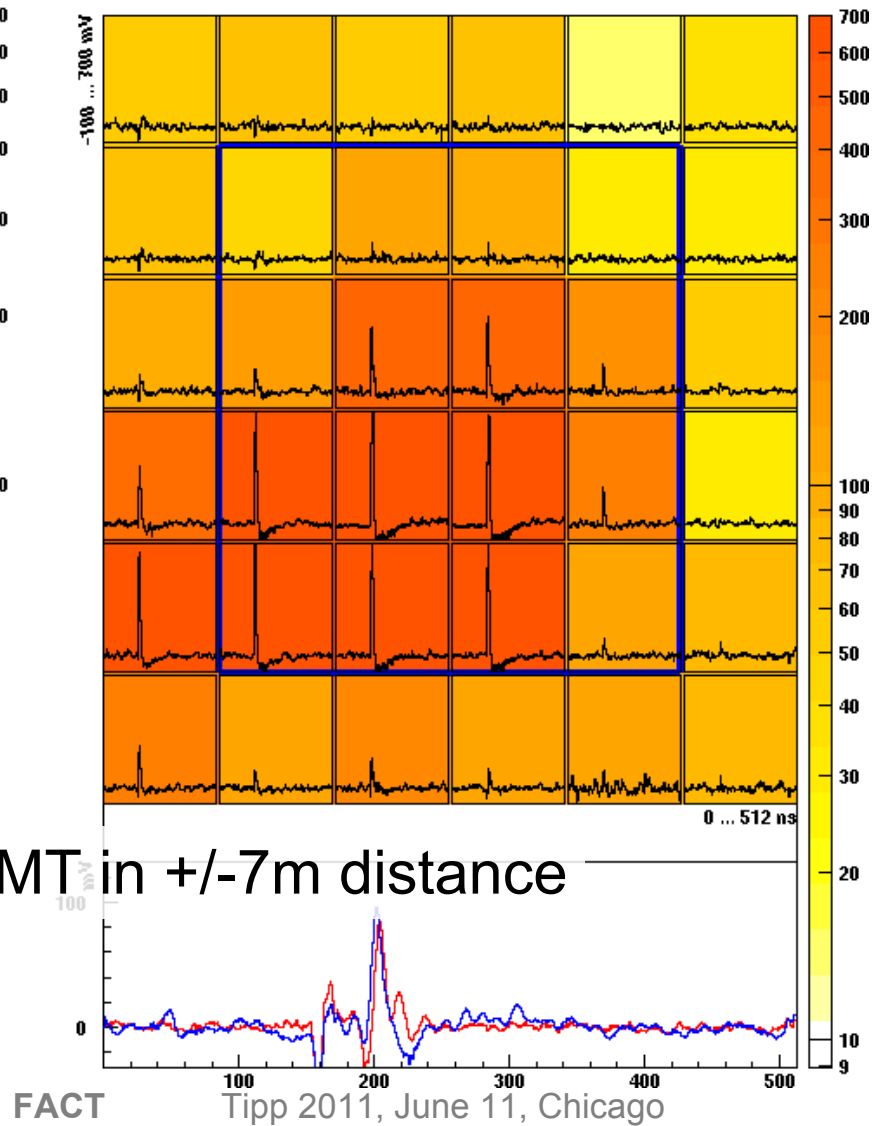
- Mirror with 80 cm focal length  $\Rightarrow 1^\circ \text{ f.o.v} / \text{pixel}$
- NSB from buildings and moonlight:  $\sim 300 \text{ MHz} / \text{G-APD}$  ( $= 1.2 \text{ GHz} / \text{pixel}$ )
- Meas. at  $22^\circ \text{ night temp.}$ , G-APD plane cooled to  $18^\circ$ , no voltage feedback

# Prototype Results (2009)

FACT run 396 event 26



FACT run 396 event 30



DRS-2 with known cross-talk problems

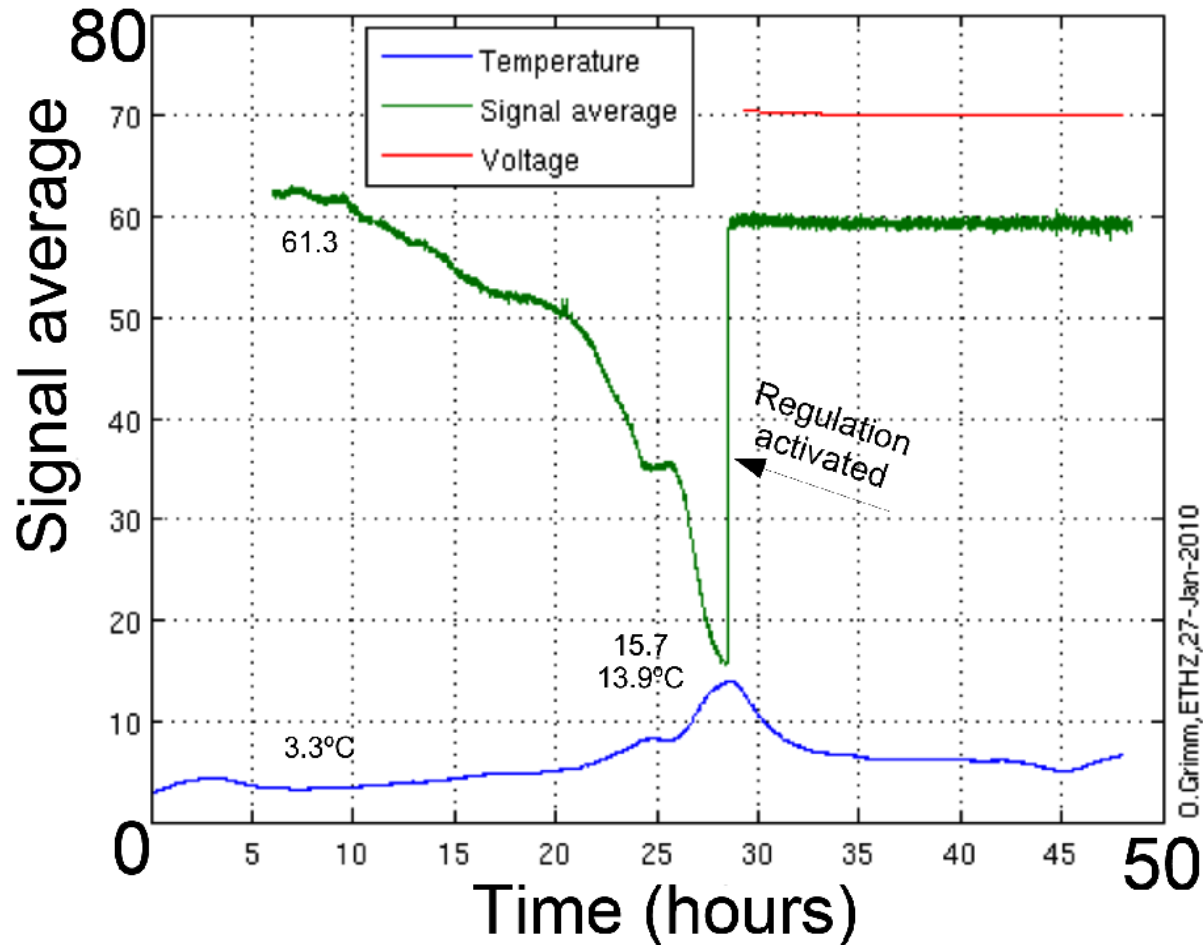


# HV Feedback System

Not sufficient to correct for gain-variation in offline analysis:  
Does also affect the trigger !!!

Instead of rather complicated Temp. stabilization, use 'feedback':

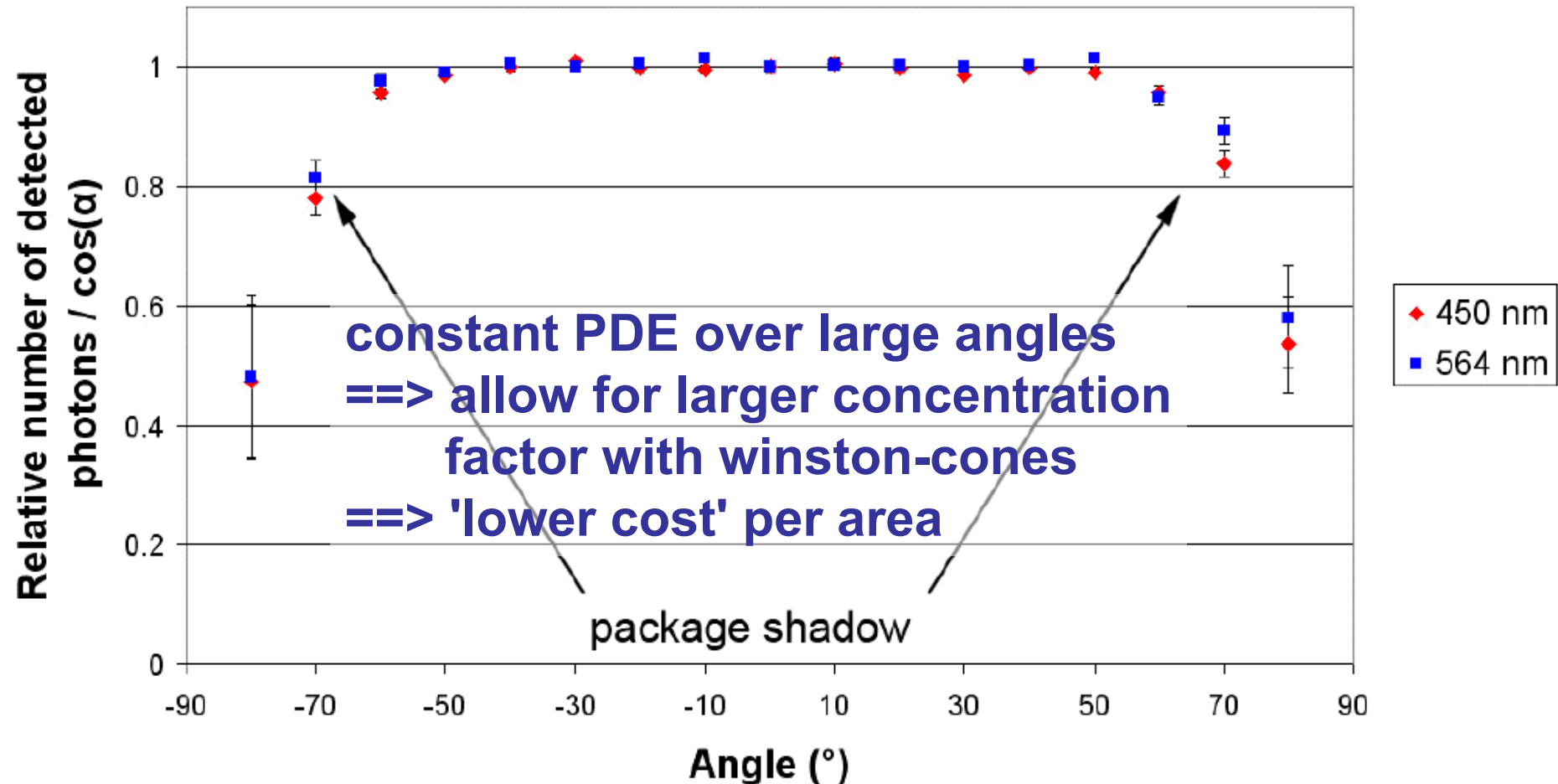
- stabilized calibration signal
- measure signal
- adapt voltage to keep signal const.



O. Grimm, ETH Z, 27-Jan-2010

# G-APD Features

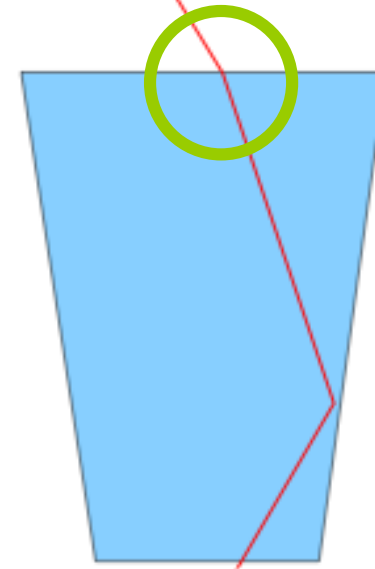
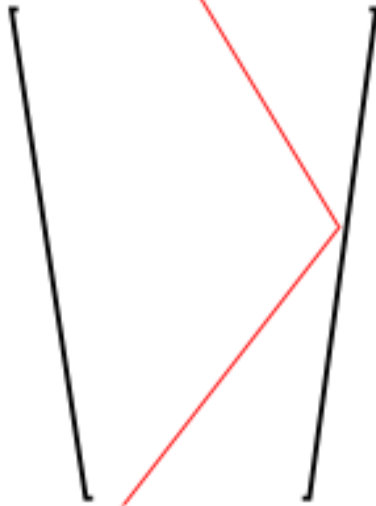
angular acceptance:



# Why Solid Light Concentrators

Liouville theorem: can not shrink phase-space

Area  $\longleftrightarrow$  Angular Distribution

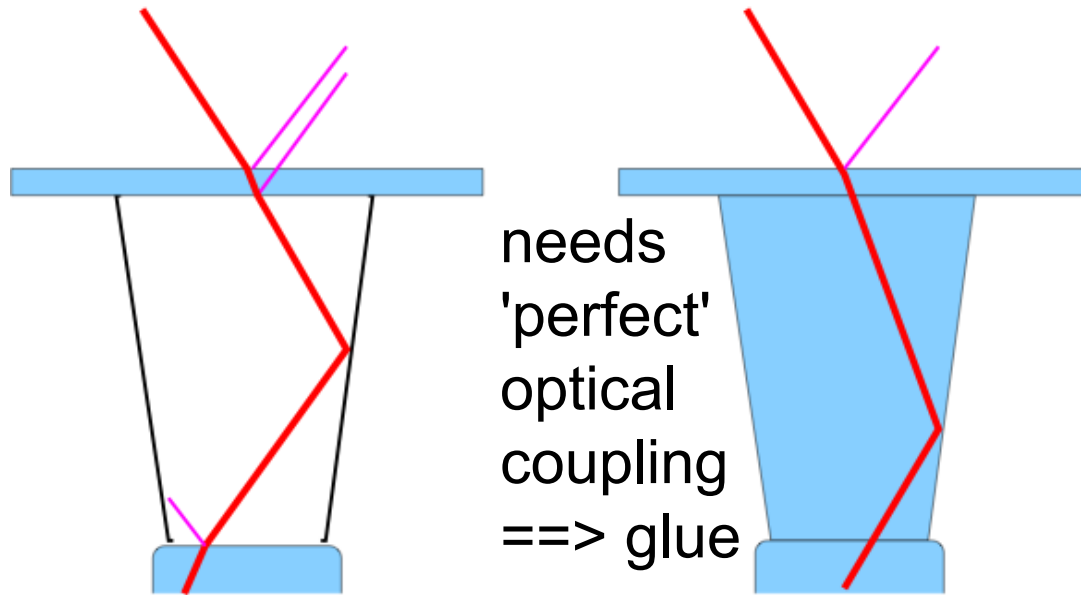


**FACT:**  
 $\sim 80\text{mm}^2$

$9.0\text{mm}^2$   
( $7.8\text{mm}^2$ )

$\Rightarrow$  Solid cones allow higher area-concentration!  
(important for photosensors with high cost/ $\text{mm}^2$ )

# Why Solid Light Concentrators



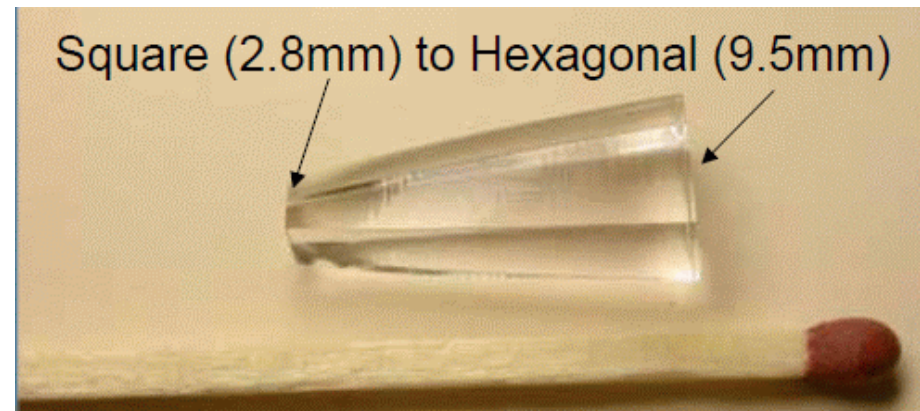
In case of sealed camera: less Frensel reflection

but: absorption

**==> do not want too large G-APD area**

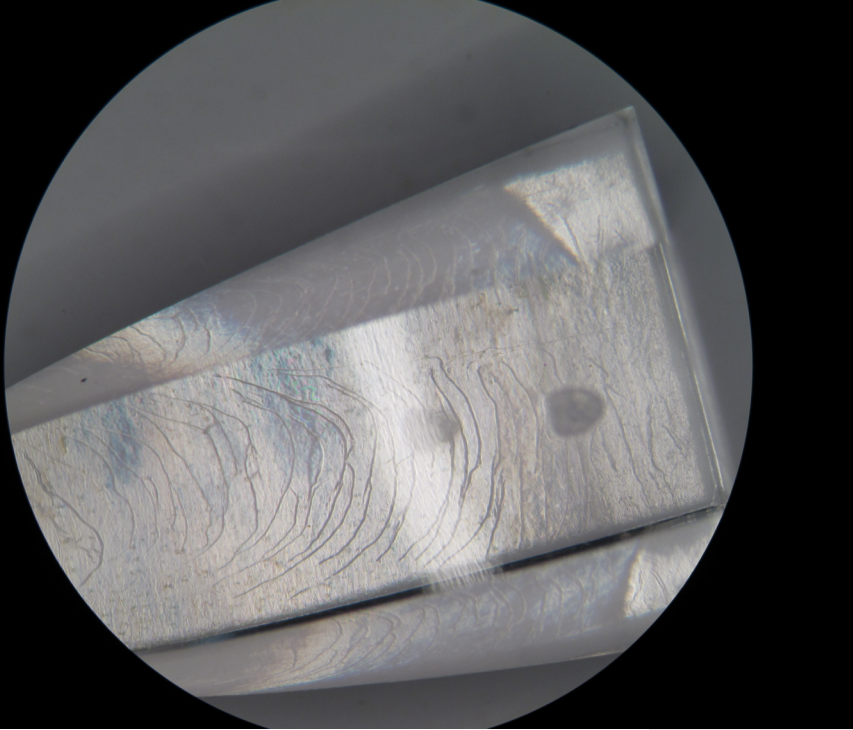
Can use inexpensive casting (UV transparent PMMA)

Complicated shapes possible  
**(FACT: square -> hexagon)**

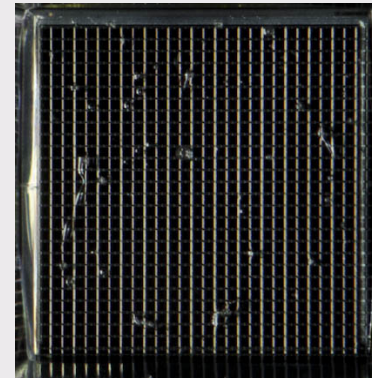




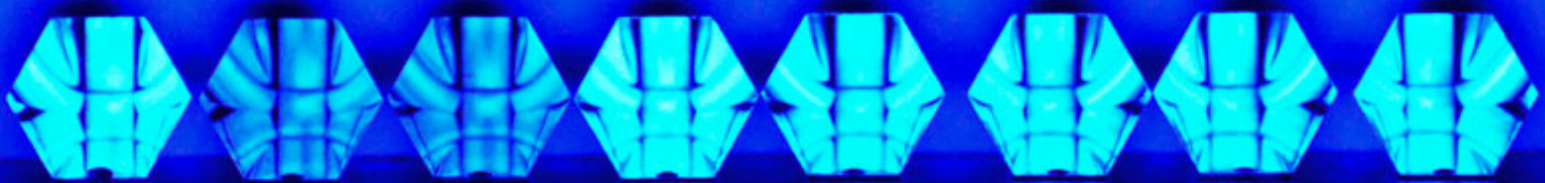
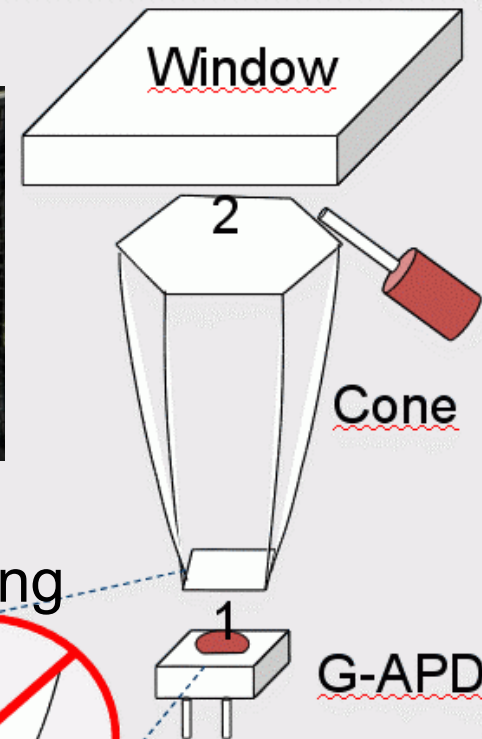
# Problems



Too high pressure during casting reduces overall transmission (also micro-bubbles)

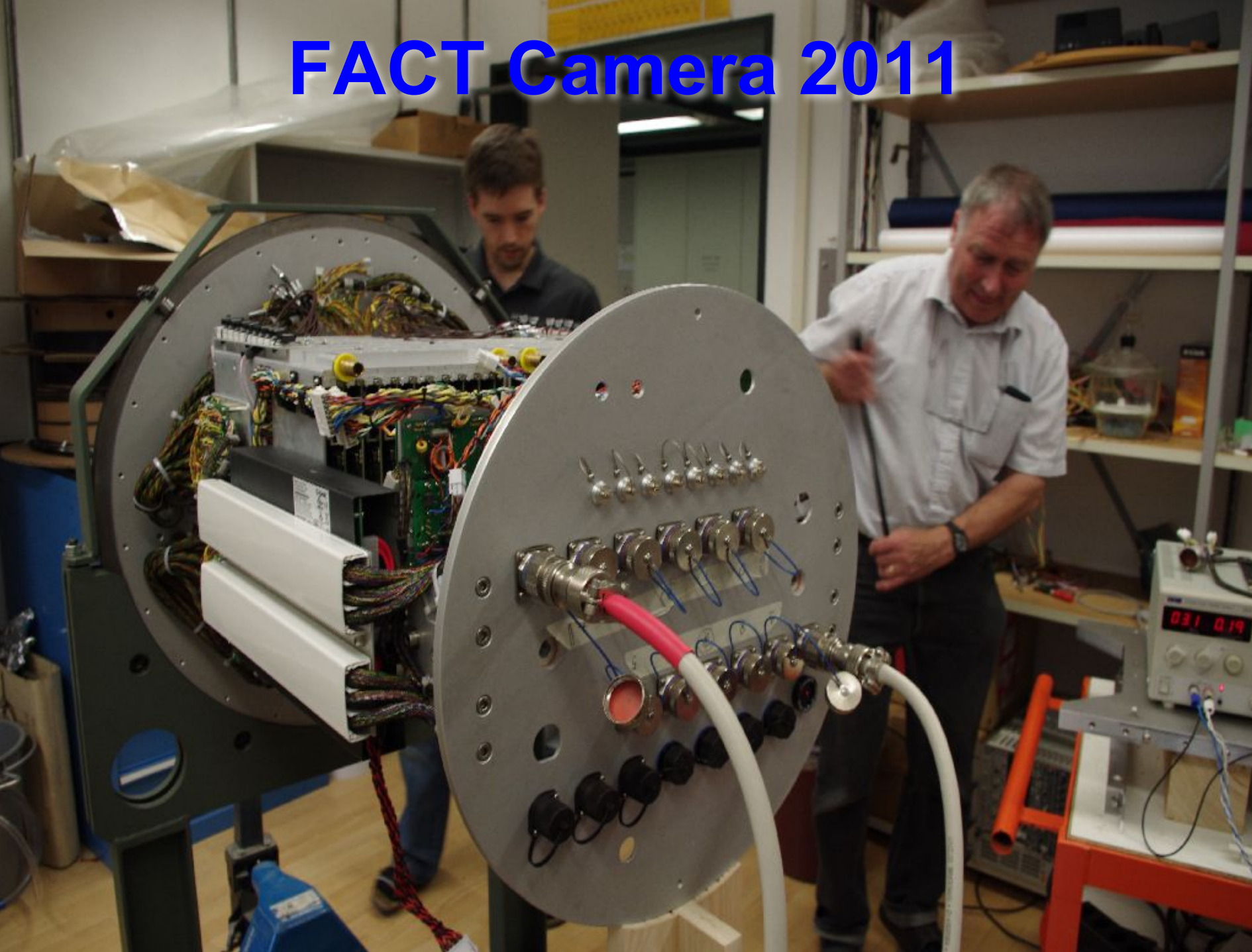


Tedious and time consuming glueing



minor PMMA impurities destroy UV transmission

# FACT Camera 2011





# FACT Camera (2011)

1440 G-APDS  
=1440 Pixels  
(0.1deg/Pixel  
4.4deg FoV Camera)

320 HV Groups  
for feedback system

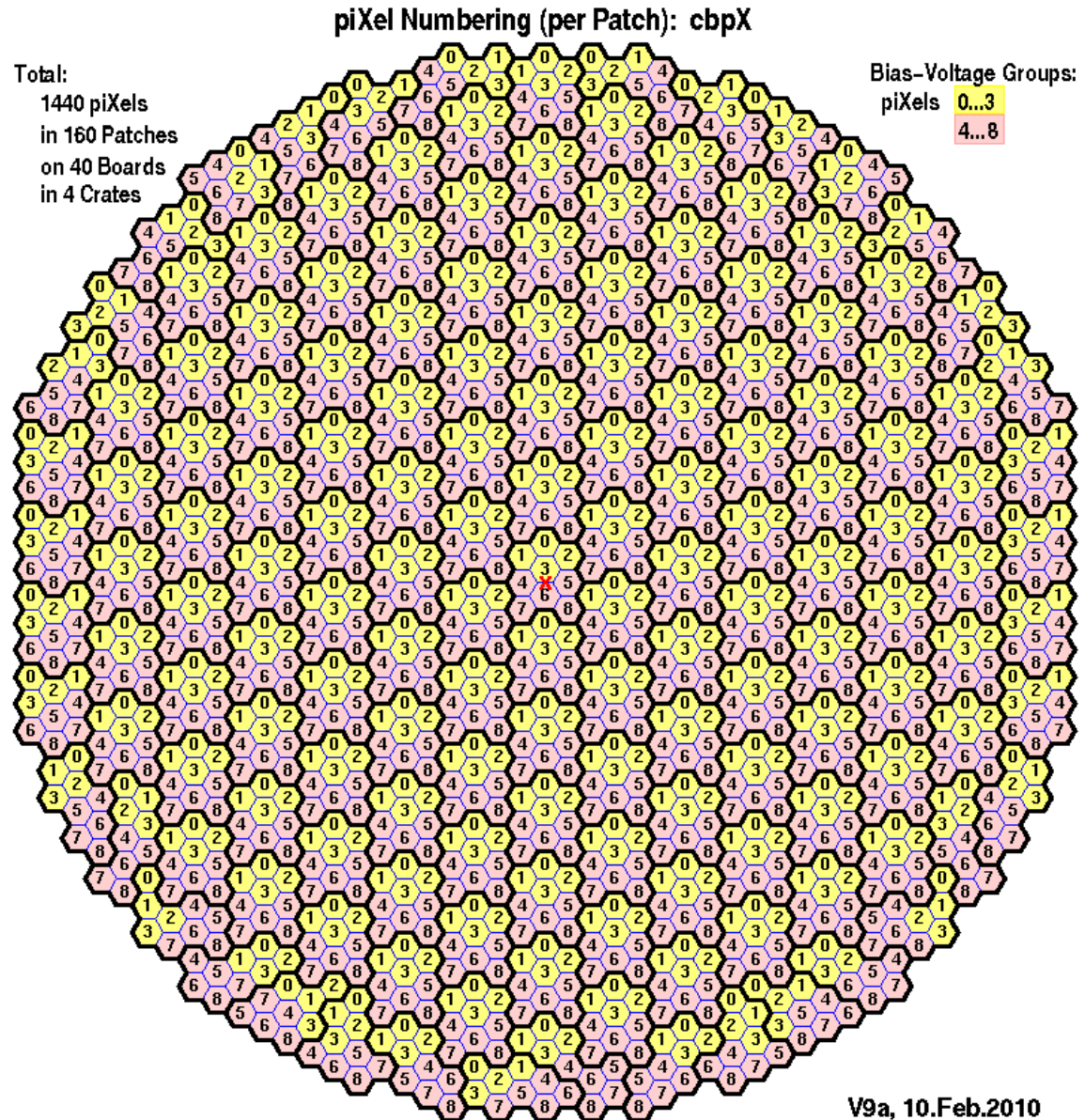
160 Trigger cells

40 Elec.Boards  
in 4 Crates

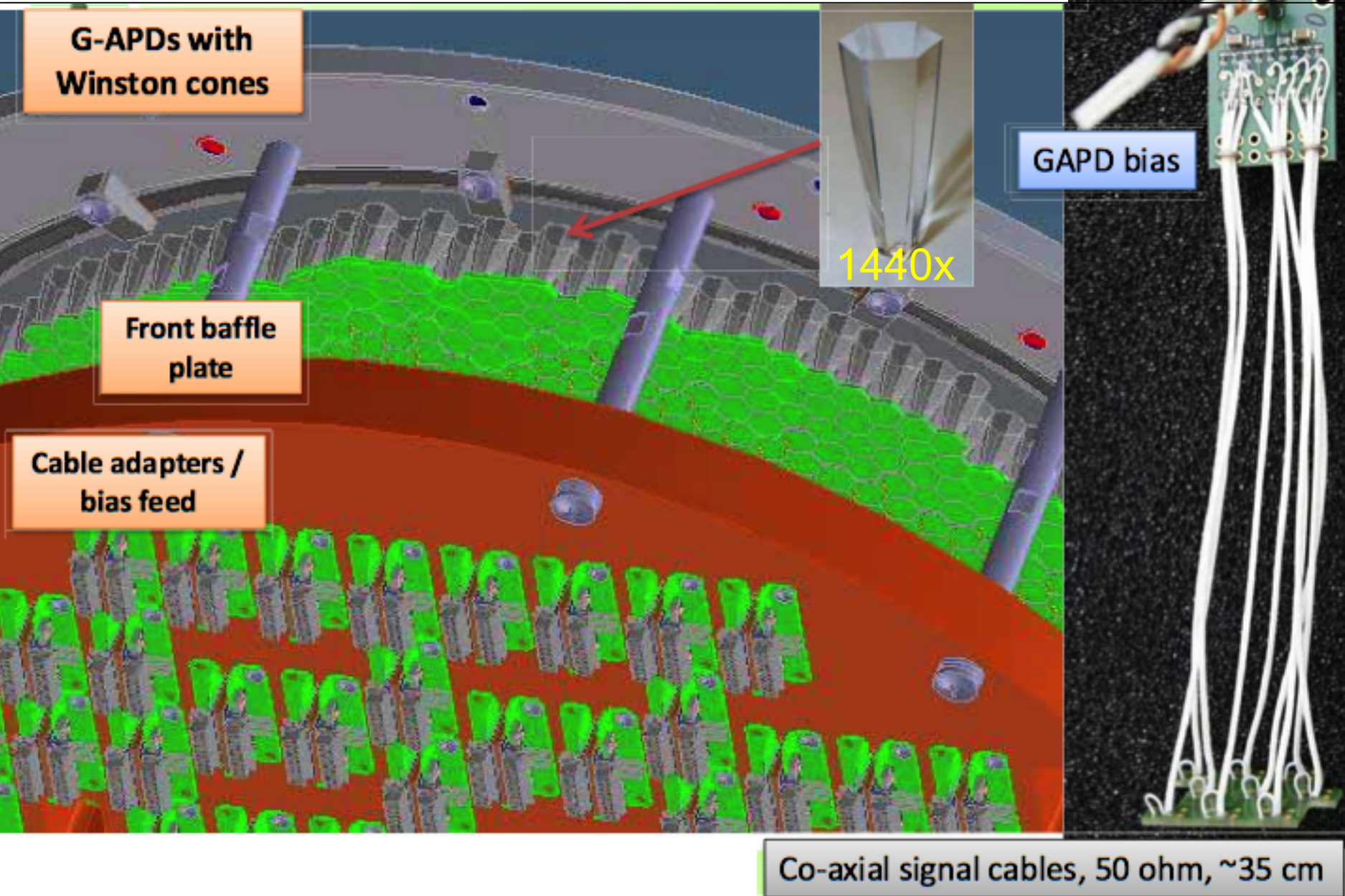
Weight: ~200kg

Power: ~1kW

IP67



# Sensor Plate





# Sensor Plate

Analogue Data and Bias-V cables

2 Boards holding  
9 G-APDs each

Solid light concentrators

Plexiglas Window

# Sensor Plate (elec. side): **Ready**



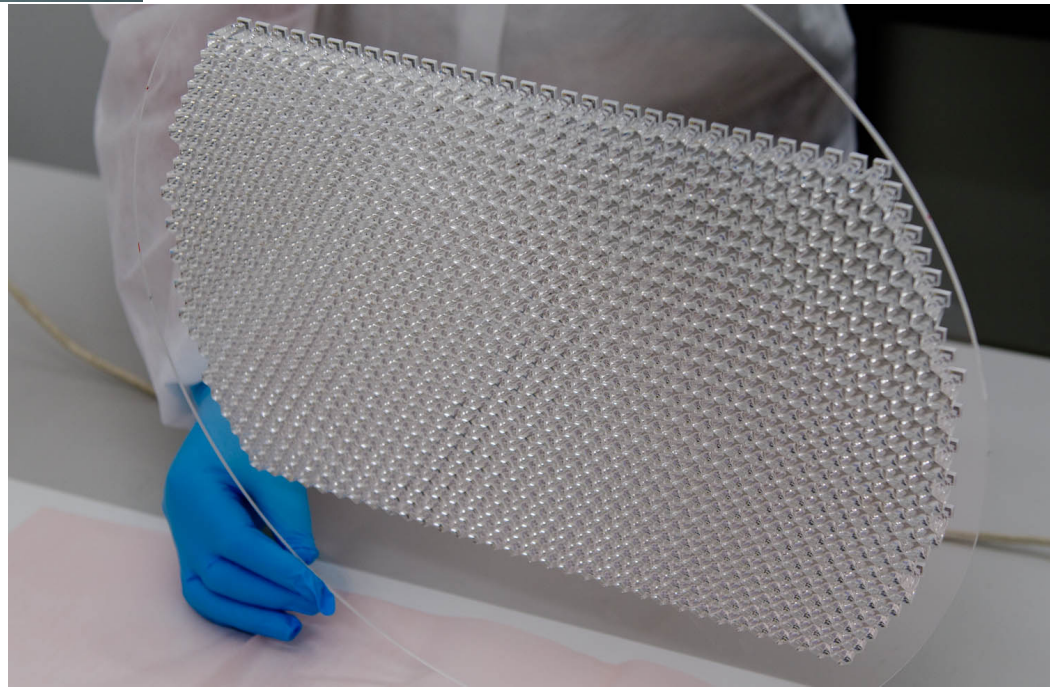


# Sensor Plate(window side): **Progress**



All ~1500 G-APDs glued to solid cones and tested

June 9th: >1000 cones  
with G-APDs glued  
to front window  
(expect all done by end of  
this conference...)



# Camera Electronics: **Ready**

Preamp.

Trigger  
Mezzanin

DAQ  
(DRS-4 & ADC)

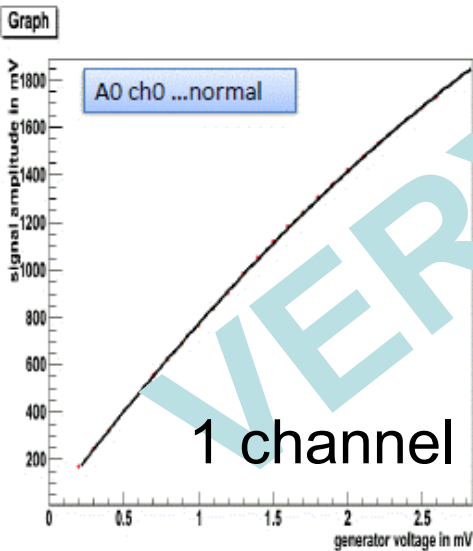
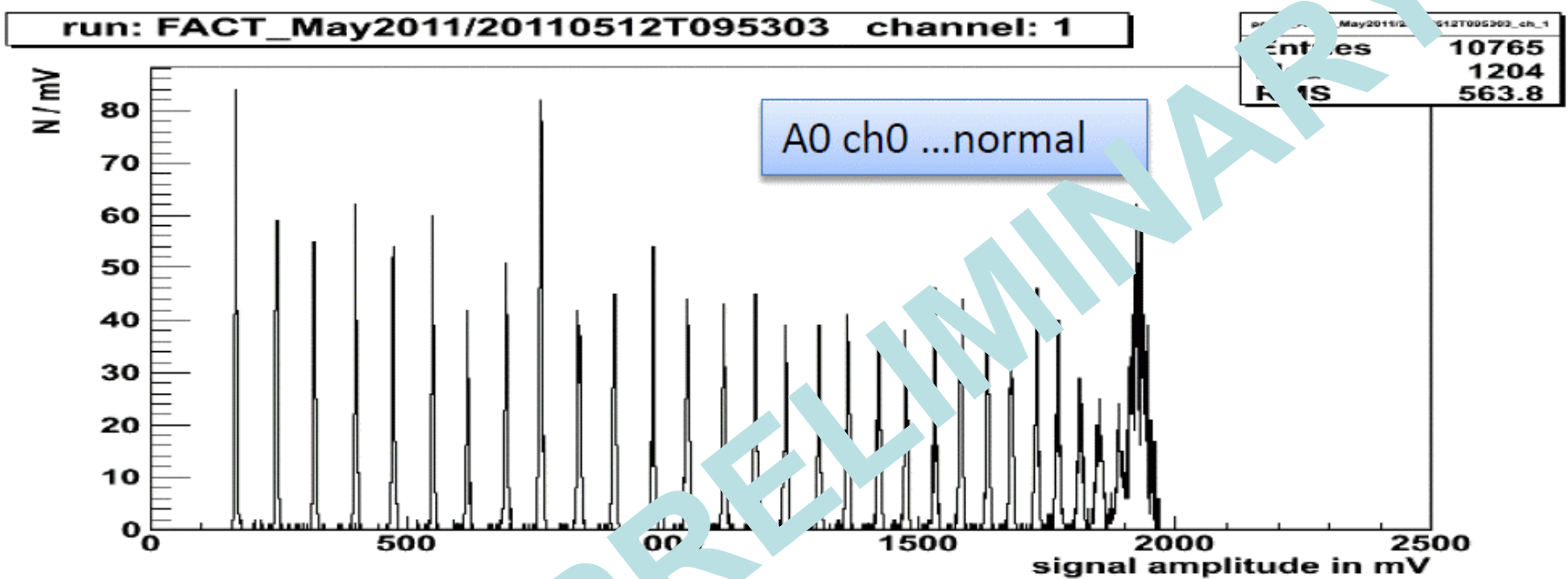
40 units X 4 crates

Trigger  
Distrib.

DAQ Ethernet

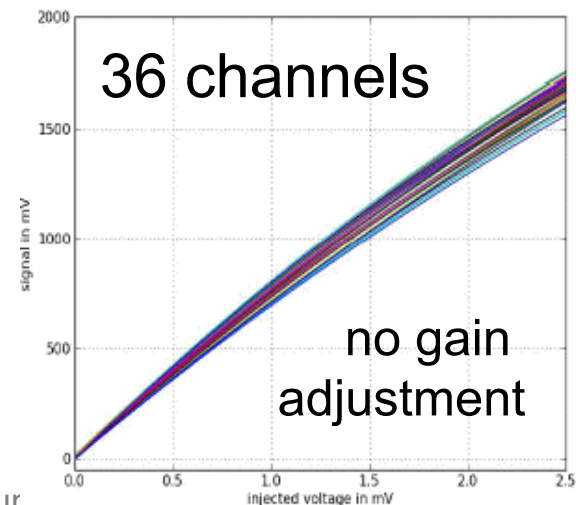


# Camera Electronics:

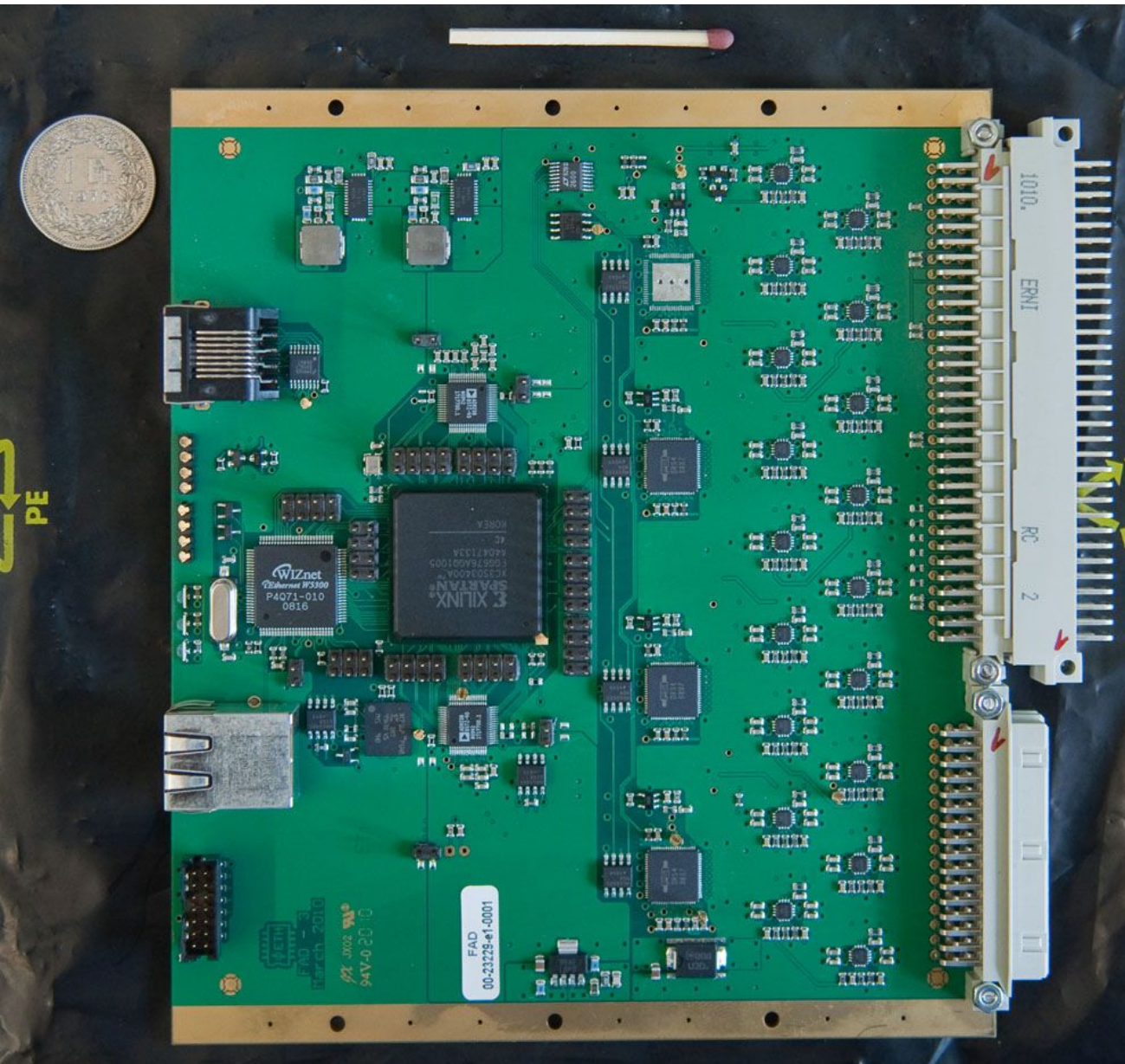


Linearity test of electronics  
cables & preamp & DRS & ADC

Very linear  
perfect fit with 2nd polynomial  
(can't see the error bars ;-)



# Data Acquisition 1: Ready



40 Boards a  
36 Pixels

each board:

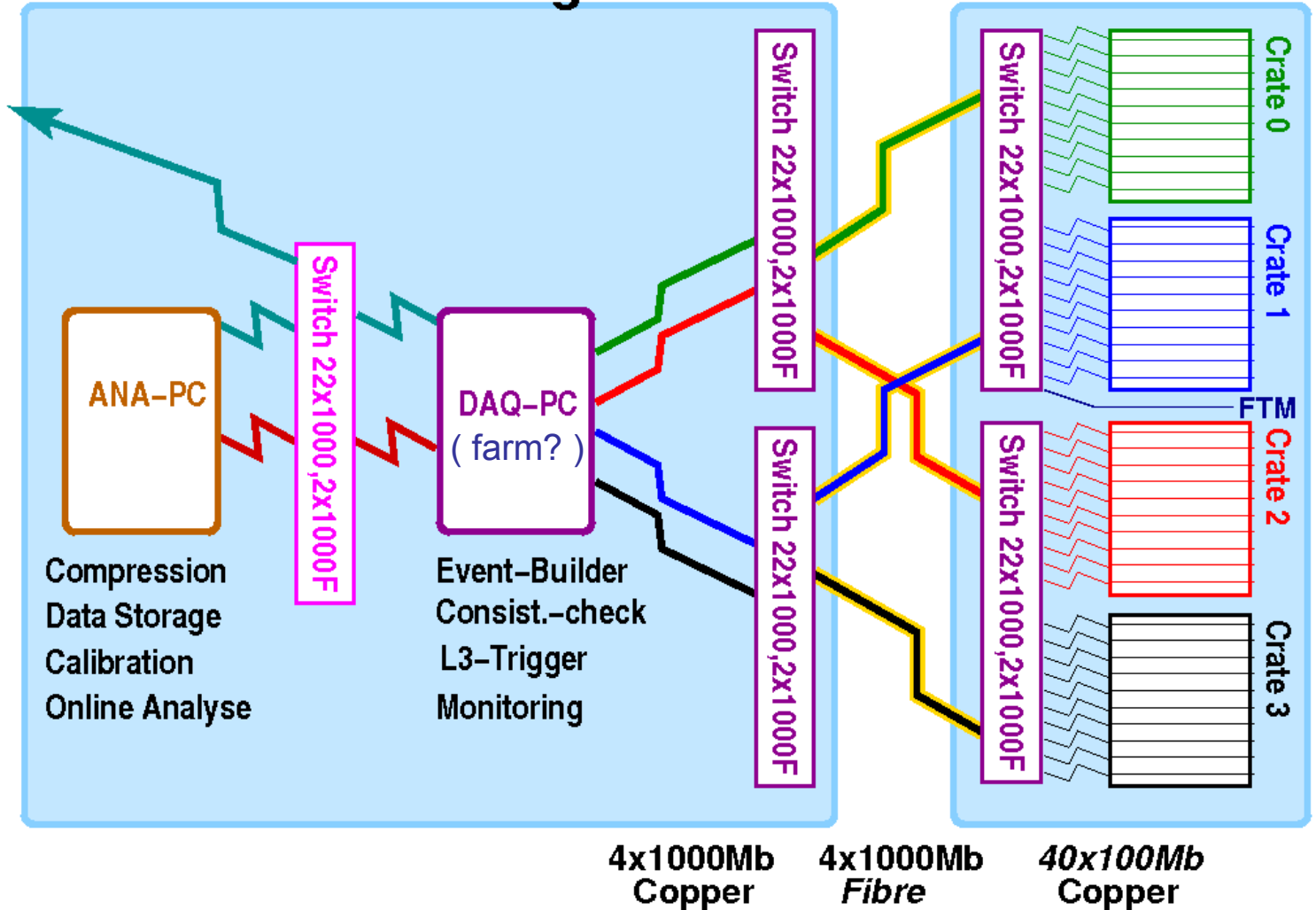
- 4x DRS-4  
analog pipeline  
(0.7 - 5 GHz)  
with 9 Channels
- 4x serial ADC  
33MHz
- FPGA, Ethernet

global Clock and  
Trigger signals

# Data Acquisition 2: Ready

## Standard Ethernet readout

## Camera



>5times higher throughput possible  
when using parallel ADCs and  
1GB/10GB ethernet components  
[but more power=> more cooling]



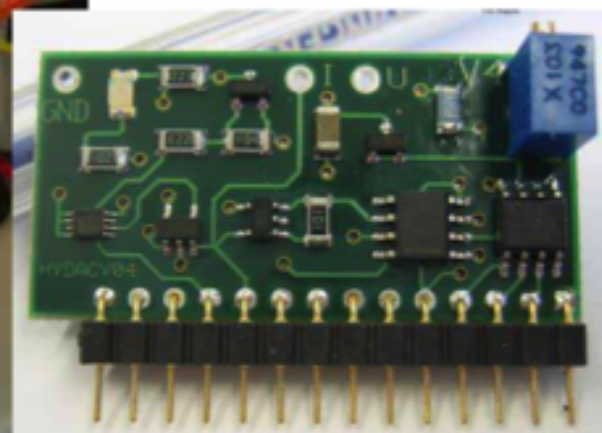
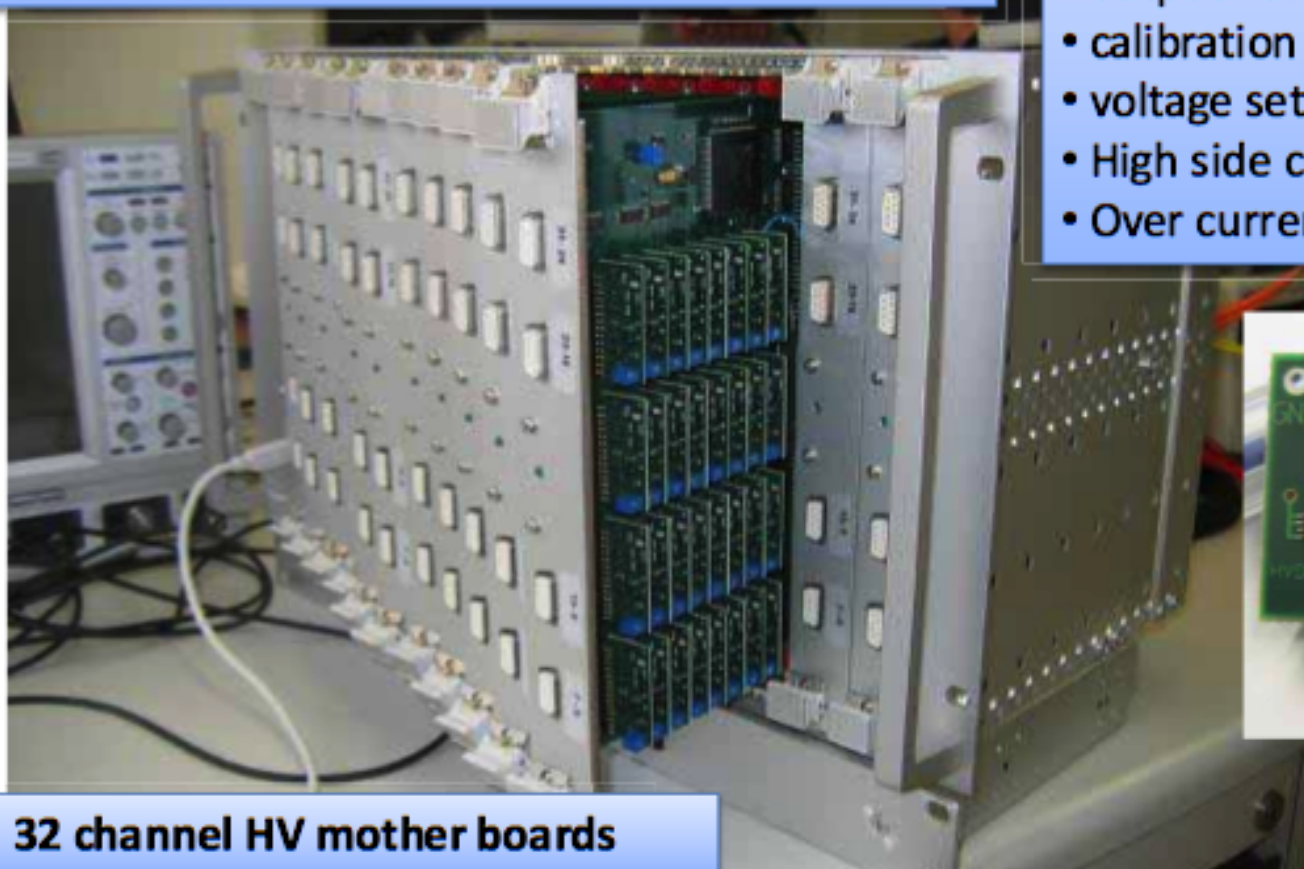
# 'HV' Power Supply: Ready

## HV crate: 320 channels

- 1 crate controller with USB interface
- 10 HV mother boards ==> **320 Channels**
- power conversion /distribution and control bus wired in the back of the crate

## Single channel board

- HV operational amplifier OPA454
- controlled by a 12 bit serial DAC (DA8034U)
- output voltage adjustable (0 – 90) V
- calibration using trim potentiometer
- voltage set precision 22 mV
- High side current monitor (HV7800)
- Over current protection, limit (1-5)mA



In counting house



# FACT Status

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- Telescope ready for comissioning

Camera:

- 'HV' built and tested
- Electronics: built, final tests going on
- solid cones: all tested
- G-APDs: all tested and glued to solid cones;  
glueing to front window almost finished
- final cabling of full camera going on

**==> Delivery to La Palma: July 2011(?)**

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